PCN Number: 2		20140408000 <mark>A</mark>					PCN Date:		e: 07	7/11/2014		
Title:	Design <mark>and</mark> TPS57114QI			_	RTE	RO1/	TPS57112	OR	TERO	01		
Customer Contact:		dmin_team@li				one:	+1(214)4				Dept:	Quality Services
Proposed 1	01/11/20	01/11/2015 Estimated San Availability				Date provided at sample request						
Change Ty	pe:											
Assemb	ly Site		\boxtimes	Desig	ın				Waf	er B	Sump S	ite
Assembly Process			X	Data Sheet				Wafer Bump Material				
Assembly Materials				Part number change				Wafer Bump Process				
Mechanical Specification				Test Site				Wafer Fab Site				
Packing/Shipping/Labeling				Test Process				Wafer Fab Materials				
									Waf	er F	ab Prod	cess
		_		PCN	Det	tails					•	

Description of Change:

Texas Instruments Incorporated is announcing a change to device design and an update to detached design and an update to device design and update to device de

Design update includes:

- Input voltage range of EN pin increased to 7V specified in the datasheet.
- Input voltage range of RT/CLK pin increased to 7V specified in the datasheet.
- NBTI issue of SENSE pin
- BOAC spacing widen from 10um to 18um
- All metal levels & BOAC must be changed (MTL1/VIA1/MTL2/VIA2/MTL3/POR/METTOP)

The product datasheet(s) is also being updated, to update switching frequency.

The following change history provides further details. These changes may be reviewed at the datasheet links provided.

Device Family	Change From:	Change To:
TPS54388-Q1	SLVSAF1B	SLVSAF1C
TPS57112-Q1	<mark>SLVSAL8</mark>	SLVSAL8A
TPS57114-01	SLVSAH5B	SLVSAH5C

The updated datasheet(s) can be accessed by the following link(s):

http://www.ti.com/product/tps54388-q1

http://www.ti.com/product/tps57112-q1

http://www.ti.com/product/tps57114-q1

Reason for Change:

Change device design to meet datasheet and to more accurately reflect device datasheet

Anticipated impact on Fit, Form, Function, Quality or Reliability (positive / negative):

Positive - Device performs per datasheet Electrical specification performance changes as indicated above.

Changes to product identification resulting from this PCN:

Chip/Die revision (2P) on shipping labels.

Example product shipping label (not actual product label)



Product Affected:

TPS54388QRTERQ1 TPS57112QRTERQ1 TPS57114QRTERQ1

Qualification Data:

This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.



TI Information Selective Disclosure

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines) TPS57114QRTERDN qual Approved04/08/2014

Product Attributes

Attributes	Qual Device: TPS57114QRTERDN			
Operating Temp Range	-40°C to +125°C			
Automotive Grade Level	Grade 1			
Wafer Fab Site	MIHO 8			
Die Revision	A3			
Assembly Site	TIM			
Package Type	QFN/SON			
Package Designator	RTE			
Ball/Lead Count	16			

⁻ QBS: Qual By Similarity

⁻ Qual Device TPS57114QRTERDN is qualified at LEVEL3-260C

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Тур	#	Test Name / Condition	Duration	Qual Device: TPS57114QRTERDN			
Test (Groι	p A - Accelerated Environment Stress Te					
PC	A1	Automotive Preconditioning Level 3	260C peak	3/880/0			
HAST	A2	Biased HAST, 130C/85%RH	130°C/85% 96 hours	3/240/0			
AC	A3	Autoclave 121C	121C / 96 hours	3/240/0			
TC	A4	Temperature Cycle, -65/150C	-65°C/+150°C/ 500 cycles	3/240/0			
			post-Temp Cycle 500 cycles	3/15/0			
PTC	A5	Power Temperature Cycle, -40/125C	-40°C to +125°C for 1000 cycles	1/50/0			
HTSL	A6	High Temp Storage Bake 150C	175°C/500 hours	1/50/0			
Test 0	Test Group B - Accelerated Lifetime Simulation Test						
HTOL	B1	Life Test, 125C	125°C/1000 hours	3/240/0			
Test 0	Test Group C - Package Assembly Integrity Tests						
Test 0	Test Group E - Electrical Verification						
HBM	E2	ESD - HBM	2000 V	1/12/0			
CDM	E3	ESD - CDM	750 V	1/3/0			
LU	E4	Latch-up	RT and 125C	1/6/0			
ED	E5	Auto Electrical Distributions	Cpk>1.67 Room, hot, and cold test	3/90/0			
Additi	Additional Tests						
MQ		Manufacturability (Auto Assembly)	(per automotive requirements)	All pass			
MSL	SL Automotive L3 Powerpad Moisture Sensitivity		260C peak	3/36/0			

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST & TC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C Grade 1 (or Q): -40°C to +125°C Grade 2 (or T): -40°C to +105°C Grade 3 (or I): -40°C to +85°C Grade 4 (or C): -40°C to +70°C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20130709-89741

Quality and Reliability Data Disclaimer

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customer should provide adequate design and operating safeguards. Quality and reliability data provided by Texas Instruments is intended to be an estimate of product performance based upon history only. It does not imply that any performance levels reflected in such data can be met if the product is operated outside the conditions expressly stated in the latest published data sheet or agreed-to customer specification for a device.

Reliability data shows characteristic failure mechanisms of the specific environmental stress as documented in the industry standards for each stress condition.

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

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